

isc Silicon NPN Power Transistor
2SD1571
DESCRIPTION

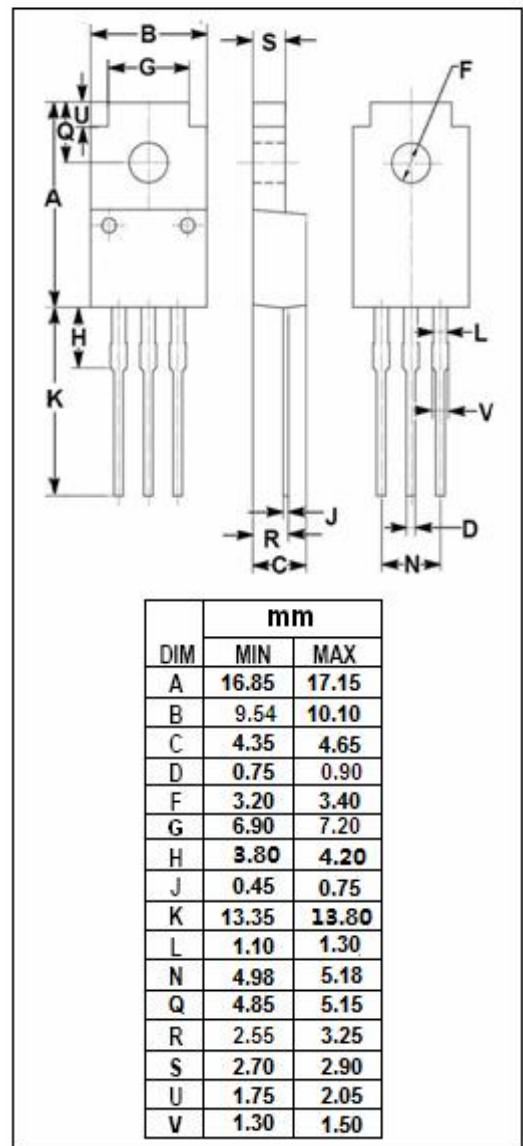
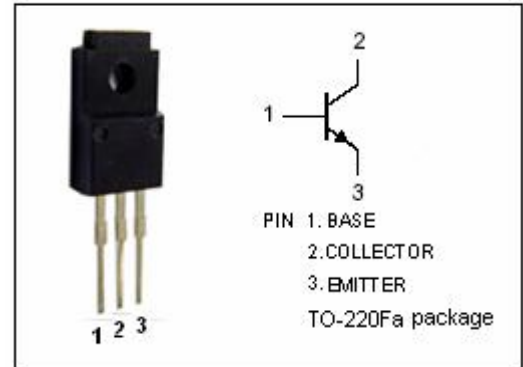
- High Collector-Base Breakdown Voltage-
: $V_{(BR)CBO} = 800V$ (Min)
- High Switching Speed
- Low Collector Saturation Voltage-
: $V_{CE(sat)} = 1.0V$ (Max.) @ $I_C = 0.5A$
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Designed for high voltage switching applications.

ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	800	V
V_{CEO}	Collector-Emitter Voltage	400	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current-Continuous	3	A
I_{CM}	Collector Current-Peak	6	A
I_B	Base Current-Continuous	1.5	A
P_C	Collector Power Dissipation @ $T_C = 25^\circ C$	30	W
	Collector Power Dissipation @ $T_a = 25^\circ C$	2	
T_J	Junction Temperature	150	$^\circ C$
T_{stg}	Storage Temperature Range	-55~150	$^\circ C$



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ELECTRICAL CHARACTERISTICS

 T_c=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA; I _B = 0	400			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 0.5A; I _B = 50mA			1.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 0.5A; I _B = 50mA			1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 800V; I _E = 0			1	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			1	mA
h _{FE-1}	DC Current Gain	I _C = 10mA; V _{CE} = 5V	8			
h _{FE-2}	DC Current Gain	I _C = 0.5A; V _{CE} = 5V	10			
f _T	Current-Gain—Bandwidth Product	I _E = 0.1A; V _{CE} = 10V		4		MHz
C _{OB}	Output Capacitance	I _E = 0; V _{CB} = 10V; f _{test} = 1.0MHz		75		pF
t _r	Rise Time	I _C = 0.5A; I _{B1} = I _{B2} = 0.05A R _L = 10 Ω; V _{CC} ≈200V P _W =20 μ s; Duty Cycle≤2%			1.0	μ s

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